

Subject card

Subject name and code	Physics of semiconductor devices, PG_00037293								
Field of study	Technical Physics								
Date of commencement of									
studies	October 2025		Academic year of realisation of subject			20277	2027/2028		
Education level	first-cycle studies		Subject group				Optional subject group		
						Subject group related to scientific research in the field of study			
Mode of study	Full-time studies		Mode of delivery			at the university			
Year of study	3		Language of instruction			Polish			
Semester of study	5		ECTS credits			5.0			
Learning profile	general academic profile		Assessment form			exam			
Conducting unit	Department Of Physics Of Electronic Phenomena -> Faculty Of Applied Physics And Mathematics -> Wydziały Politechniki Gdańskiej								
Name and surname	Subject supervisor								
of lecturer (lecturers)	Teachers								
Lesson types and methods	Lesson type	Lecture	Tutorial	Laboratory	ory Project		Seminar	SUM	
of instruction	Number of study hours	30.0	30.0	0.0	0.0		0.0	60	
	E-learning hours inclu	uded: 0.0							
Learning activity and number of study hours	Learning activity		Participation in didactic classes included in study olan		Participation in consultation hours		tudy	SUM	
	Number of study hours	60		5.0		60.0		125	
Subject objectives	The aim of this course is to understand fundamental physics of semiconductors and devices based on semiconductors.								
Learning outcomes	Course outcome		Subject outcome			Method of verification			
	[K6_U01] learns independently, obtains information from literature, databases and other properly selected sources		Student knows how to use literature and databases in semiconductors and semisonductor devices			[SU2] Assessment of ability to analyse information			
	[K6_W02] has systematized knowledge of the basics of physics, including mechanics, thermodynamics, electricity and magnetism, optics, atomic and particle physics, solid-state physics, nuclear and elementary particle physics		The knowledge allows to analyze selected problems concerned semiconductors and semiconductor devices in real world			[SW1] Assessment of factual knowledge			
	[K6_W07] has knowledge of the construction and operation of physical instruments, measurement and research equipment					[SW1] Assessment of factual knowledge			
Subject contents	Introduction to solid state physics (structure of crystalline solids, types of chemical bonds in solids, phonons, Fermi-Dirac and Bose-Einstein statistics, Fermi level in metals, electrical conduction in metals, band structure of solids, effective mass). Introduction to semiconductors (electronic hole, Fermi level in semiconductors, direct and indirect energy gap, equilibrium concentration, intrinsic and extrinsic semiconductors, donors and acceptors, generation and recombination of charge carriers, Hall effect). Introduction to semiconductor electrodynamics (mobility of carries, drift and diffusion equations, Poisson equation, continuity equation, space charge, dielectric relaxation, ambipolar transport equation). Semiconductor devices (Hall efect sensor, diode, transistor, LED, diode laser, photoresistor, photovoltaic cell). Injection, termionic and optical effects in devices.								
Prerequisites and co-requisites	Completed courses in "Electricity and magnetism" and "Introduction to modern physics"								
Assessment methods	Subject passing criteria		Passing threshold			Percentage of the final grade			
and criteria	Written exam		50.0%		60.0%				
	Exercises					40.0%			

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Recommended reading	Basic literature	C. Kittel "Introduction to solid state physics", PWN A. van der Ziel "Fundaments of solid state electronics" WNT J. Hennel "Introduction to semiconductor elektronics" WNT			
	Supplementary literature	A.K. Jonscher "Fundaments of semiconductor devices" WNT			
	eResources addresses	Adresy na platformie eNauczanie:			
Example issues/ example questions/ tasks being completed	Electronic structure of solid states Intrinsic and extrinsic semiconductors Diode				
	4. Transistor 5. Laser diode				
Work placement	Not applicable				

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